



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

BMS3003 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)1}=5.0m\Omega$ (typ.)
- Input capacitance $C_{iss}=13200pF$ (typ.)
- 4V drive

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-60	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-78	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s, \text{ duty cycle} \leq 1\%$	-312	A
Allowable Power Dissipation	PD		2.0	W
		$T_c=25^\circ C$	40	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$
Avalanche Energy (Single Pulse) *1	E_{AS}		420	mJ
Avalanche Current *2	I_{AV}		-60	A

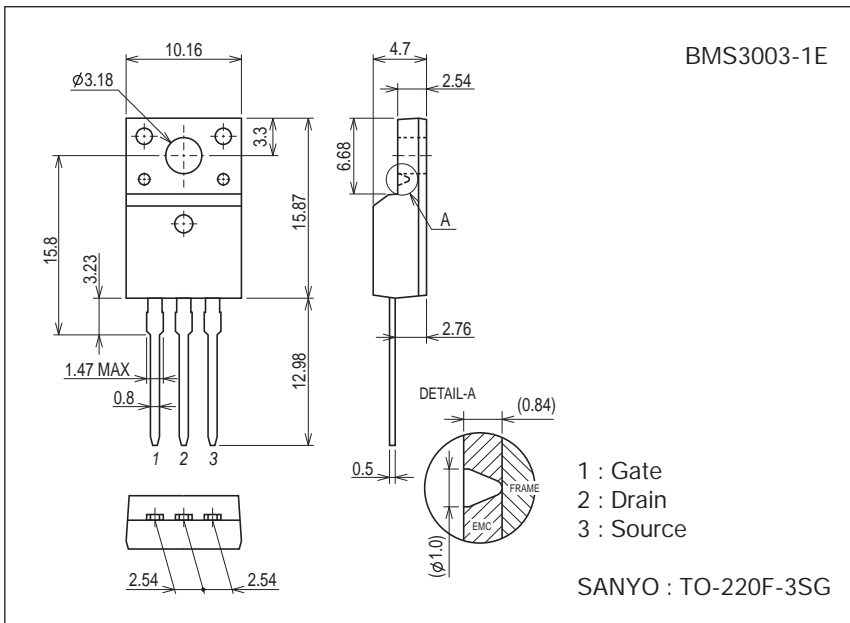
Note : *1 $V_{DD}=-36V, L=100\mu H, I_{AV}=-60A$ (Fig.1)

*2 $L \leq 100\mu H, \text{ Single pulse}$

Package Dimensions

unit : mm (typ.)

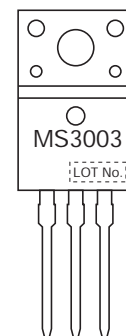
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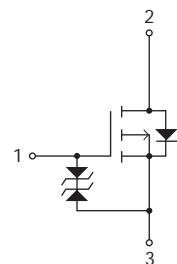
Product & Package Information

- Package : TO-220F-3SG
- JEITA, JEDEC : SC-67
- Minimum Packing Quantity : 50 pcs./magazine

Marking



Electrical Connection



BMS3003

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min.	typ.	max.	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-60V, VGS=0V			-10	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-39A		130		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-39A, VGS=-10V		5.0	6.5	mΩ
	RDS(on)2	ID=-39A, VGS=-4V		6.5	9.0	mΩ
Input Capacitance	Ciss			13200		pF
Output Capacitance	Coss	VDS=-20V, f=1MHz		1300		pF
Reverse Transfer Capacitance	Crss			950		pF
Turn-ON Delay Time	td(on)	See Fig.2		90		ns
Rise Time	tr			360		ns
Turn-OFF Delay Time	td(off)			1200		ns
Fall Time	tf			680		ns
Total Gate Charge	Qg				285	
Gate-to-Source Charge	Qgs	VDS=-36V, VGS=-10V, ID=-78A		35		nC
Gate-to-Drain "Miller" Charge	Qgd			70		nC
Diode Forward Voltage	VSD	IS=-78A, VGS=0V		-0.95	-1.5	V
Reverse Recovery Time	trr	See Fig.3		150		ns
Reverse Recovery Charge	Qrr	IS=-78A, VGS=0V, di/dt=-100A/μs		470		nC

Fig.1 Unclamped Inductive Switching Test Circuit

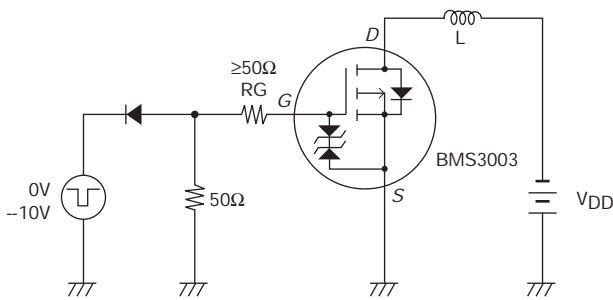


Fig.2 Switching Time Test Circuit

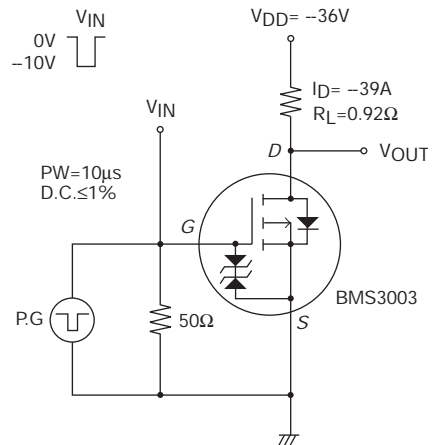
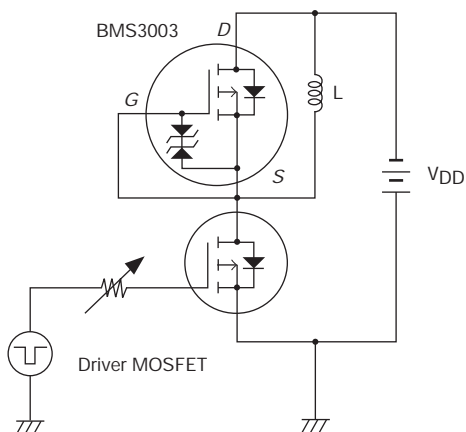
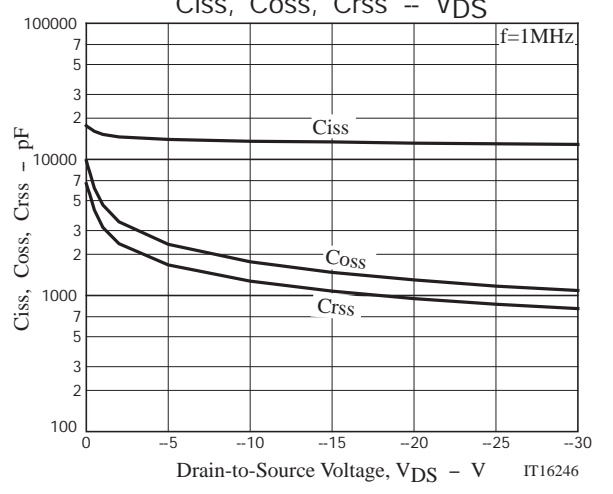
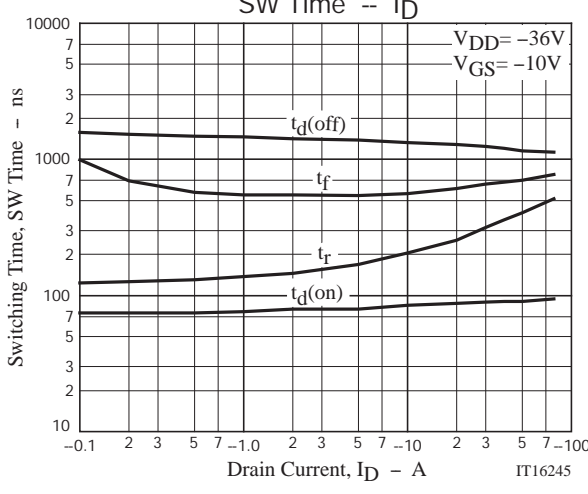
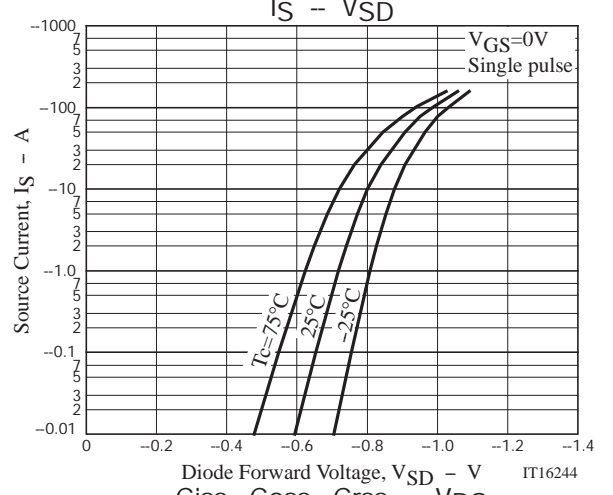
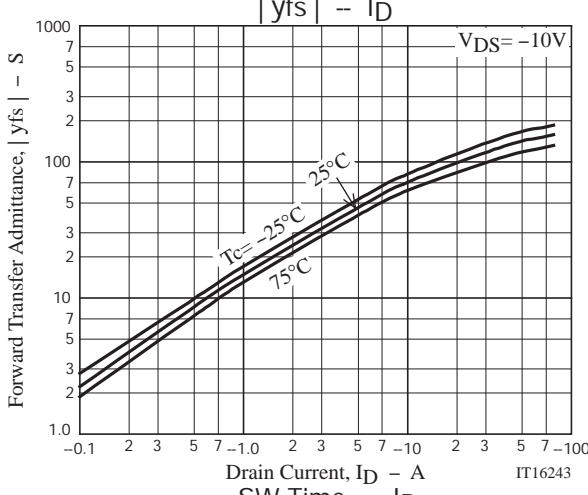
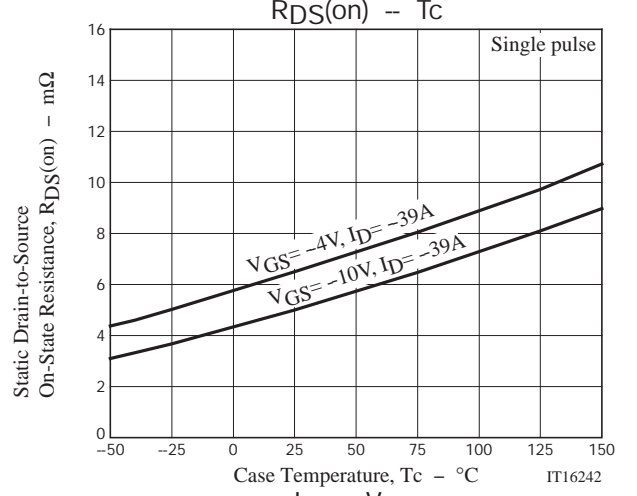
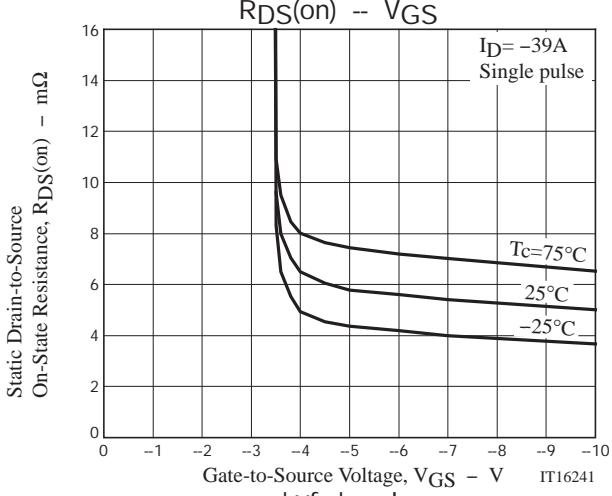
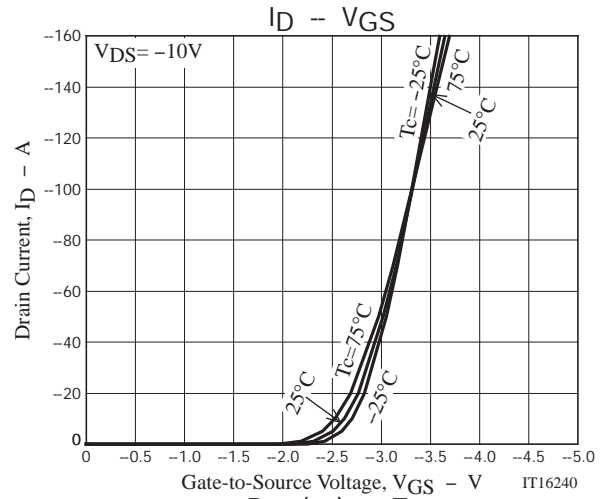
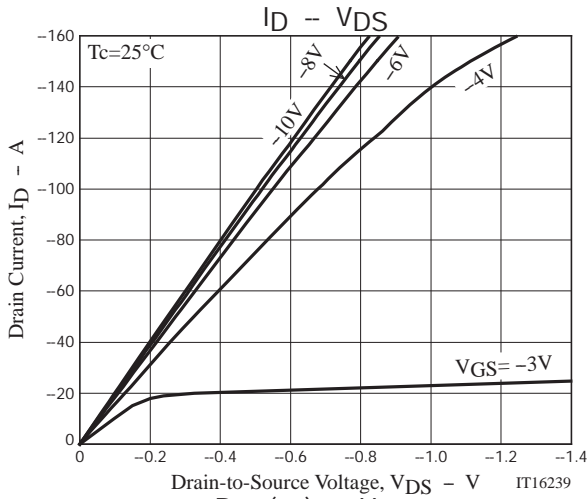


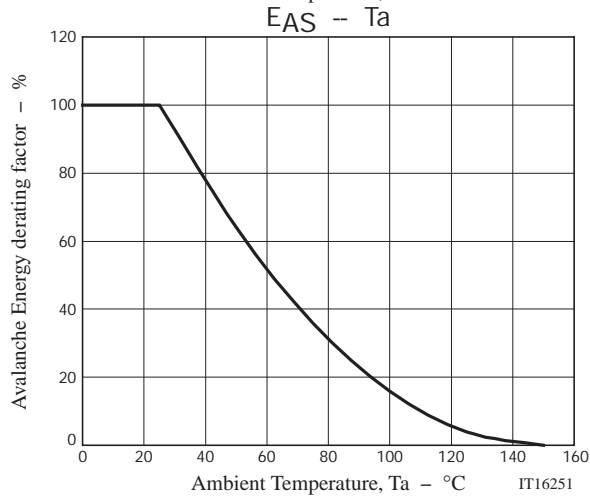
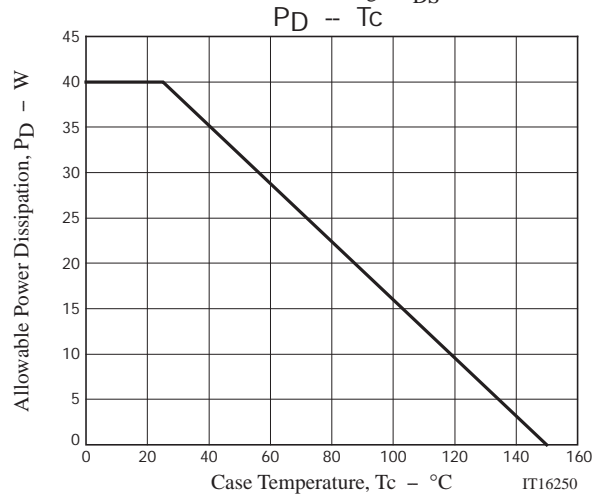
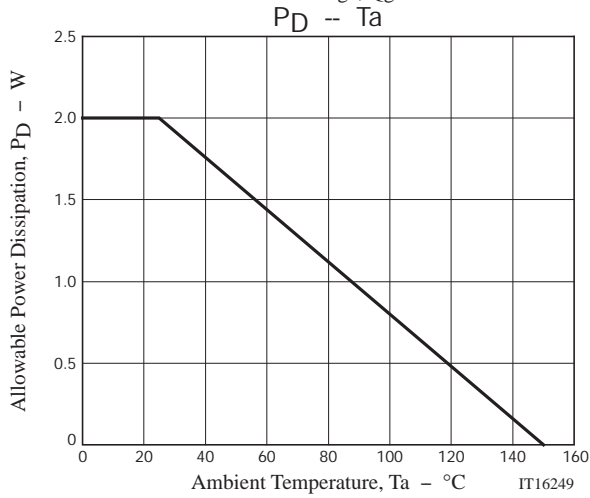
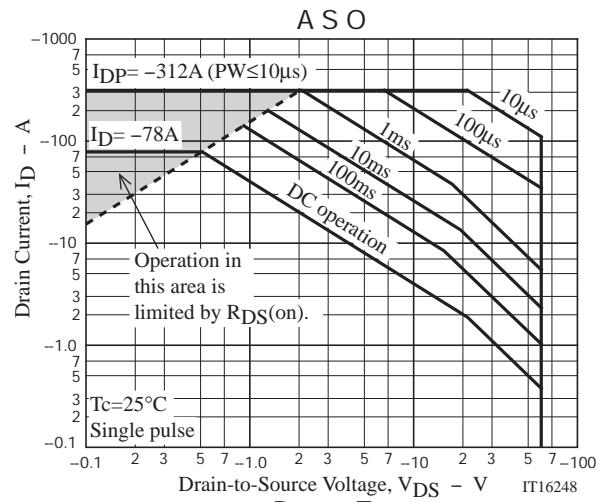
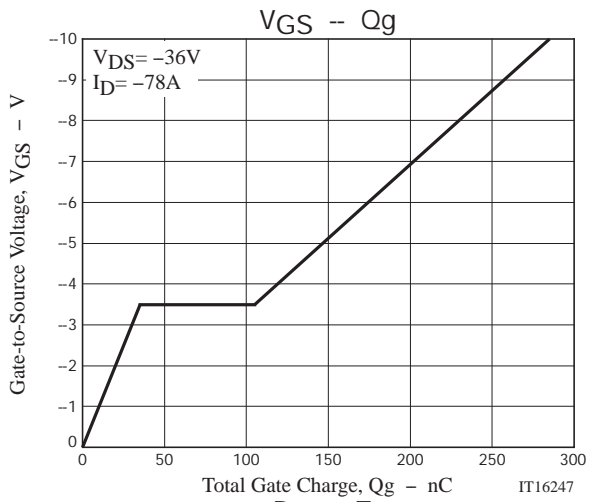
Fig.3 Reverse Recovery Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
BMS3003-1E	TO-220F-3SG	50pcs./magazine	Pb Free





Magazine Specification

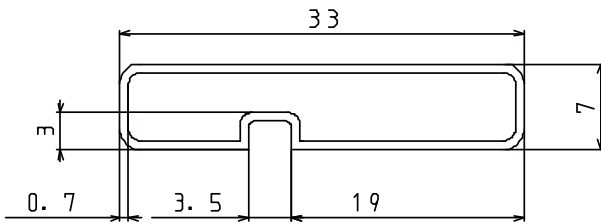
BMS3003-1E

1. Packing Format

Package Name	Magazine Name	Maximum Number of devices contained (pcs)			Packing format	
		Magazine	Inner box	Outer box	Inner BOX	Outer BOX
TO-220F-3SG	TO-220F	50	1,000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178

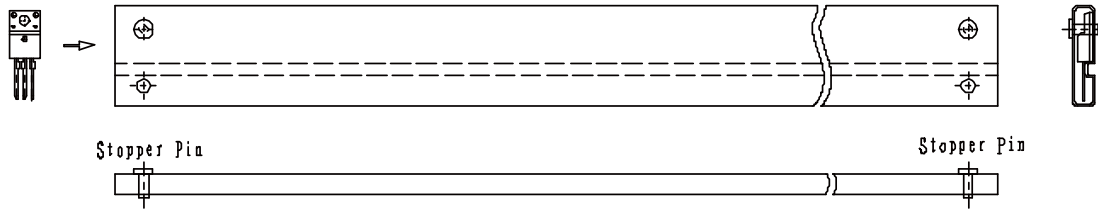
2. Magazine dimensions

(unit:mm)

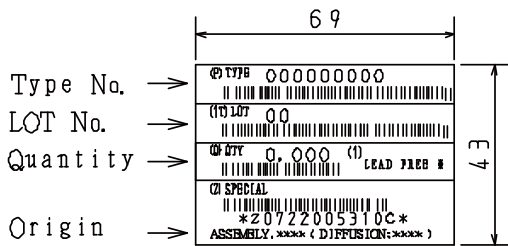


Tolerance=±0.3mm
 Thickness=0.7±0.2mm
 Length =532.5±2mm
 Material =PVC (Antistatic treatment)

3. Storage method to magazine

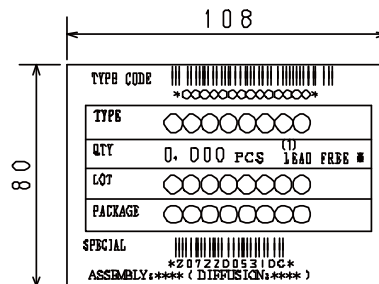


4. Inner box label (unit:mm)



5. Outer box label (unit:mm)

It is a label at the time of factory shipments.
 The form of a label may change in physical
 distribution process.



NOTE (1)

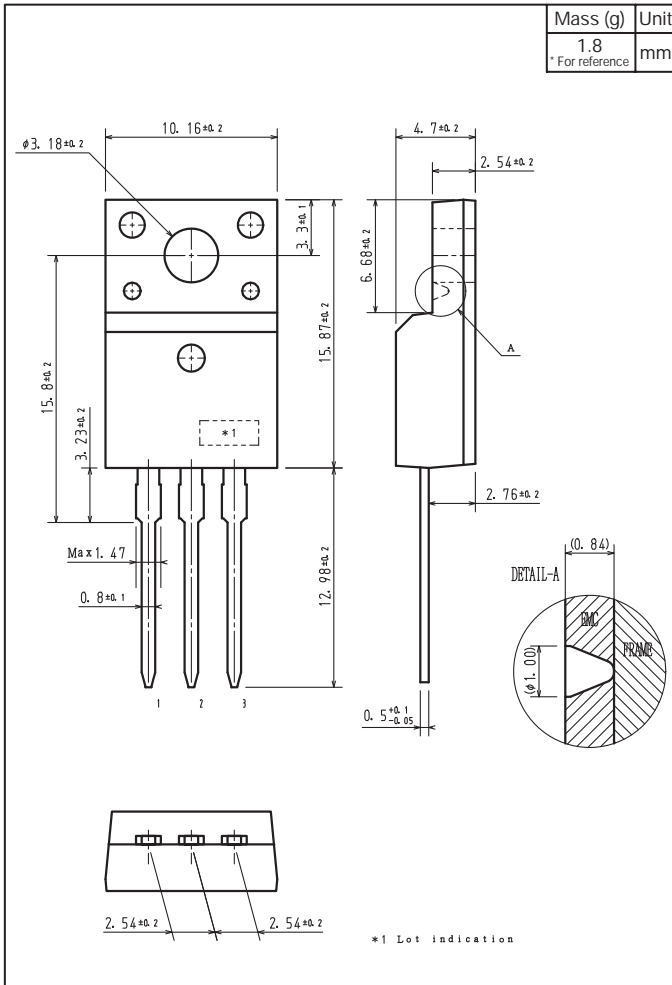
The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A

BMS3003

Outline Drawing

BMS3003-1E



Note on usage : Since the BMS3003 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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